



ESD-SIC bv

SILICONCARBIDE (α -SiC) DATASHEET

Chem. Formula:	SiC
Rel. Molar mass:	40,097 g/mol
Chem. composition:	70,05% Si 29,95% C
Density:	3,21 g/cm ³
Hardness:	9,5-9,75 (Mohs) Hk 0,1 2100-2900 (Knoop) Hv 4020 kg/mm ²
Melting point:	2830 \pm 40 °C (decomposition)
Heat capacity:	0,67 J/g ^o K (20 °C) 1,27 J/g ^o K (1000 °C)
Thermal conductivity:	150 kJ/mh ^o K (20 °C) 54 kJ/mh ^o K (1400 °C)
Linear thermal expansion:	4,7x10 ⁻ °K ⁻¹ (20-1400 °C α -SiC)
Standard heat of formation:	ΔH° 298K = -71,6 \pm 6,3 kJ/mol
Entropie:	S ^o 298K = 16,50 \pm 0,13 J/mol ^o K
Specific electrical resistivity:	0,1 Ω cm - 10 ¹² Ω cm
Modifications:	α -SiC; several hexagonal and rhomboedric polytypes (6 H, 15 R, 4 H u. a.) β -SiC, cubic (3C), metastable, transformation in α -SiC above 1900 °C
Color:	depending on purity and crystal structure: colourless, yellow, green, blue, black
Index of refraction:	n _o = 2,647-2,649 n _E = 2,688-2,693 (Na 589 nm, 20 °C)



ESD-SIC bv
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Chemical properties:

Resistant to acids and alkalies.

Stable during heating in presence of air up to 1500 °C

Is decomposed by melting alkalies such as

$\text{Na}_2\text{O}_2 + \text{Na}_2\text{CO}_3$ or $\text{KNO}_3 + \text{Na}_2\text{CO}_3$.